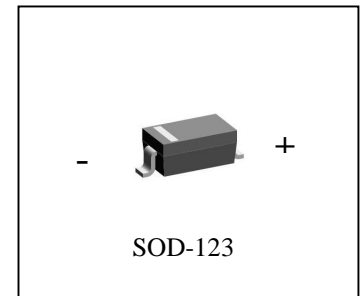


SCHOTTKY BARRIER DIODE

B0520W/B0530W/B0540W
FEATURES

- Low Forward Voltage Drop
- Guard Ring Construction for Transient Protection
- High Conductance
- Also Available in Lead Free Version


Maximum Ratings @Ta=25°C

Parameter	Symbol	B0520W	B0530W	B0540W	Unit
Peak Repetitive Peak Reverse Voltage	V_{RRM}				
Working Peak Reverse Voltage	V_{RWM}	20	30	40	V
DC Blocking Voltage	V_R				
RMS Reverse Voltage Reverse Voltage (DC)	$V_{R(RMS)}$	14	21	28	V
Average Rectified Output Current	I_o	0.5			A
Forward Current Surge Peak	I_{FSM}	5.5			A
Power Dissipation	P_D	500			mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	250			°C/W
Junction Temperature	T_j	125			°C
Storage Temperature	T_{STG}	-55~+150			°C
Voltage Rate of Change	dv/dt	1000			V/ μ s

Electrical Characteristics @Ta=25°C

Parameter	Symbol	B0520W	B0530W	B0540W	Unit	Test Conditions
Minimum reverse breakdown voltage	$V_{(BR)}$	20	--	--	V	$I_R=250\mu A$
		--	30	--		$I_R=200\mu A$
		--	--	40		$I_R=20\mu A$
Forward voltage	V_{F1}	0.32	0.375	--	V	$I_F=0.1A$
	V_{F2}	0.385	0.430	0.510		$I_F=0.5A$
	V_{F3}	--	--	0.62		$I_F=1A$
Reverse current	I_{R1}	75	--	--	μA	$V_R=10V$
	I_{R2}	--	20	--		$V_R=15V$
Reverse current	I_{R3}	250	--	10	μA	$V_R=20V$
	I_{R4}	--	130	--		$V_R=30V$
	I_{R5}	--	--	20		$V_R=40V$
Capacitance between terminals	C_T	--	--	170	pF	$V_R=0, f=1MHz$

B0520W/B0530W/B0540W

Typical Characteristics

